

SK12~SK11(SS12~SS110) SMA

Schottky rectifier

Major Ratings and Characteristics

I _{F(AV)}	1.0 A
V_{RRM}	20 V to 100 V
I _{FSM}	30 A
V _F	0.55 V , 0.70 V, 0.85V
T _j max.	150 °C

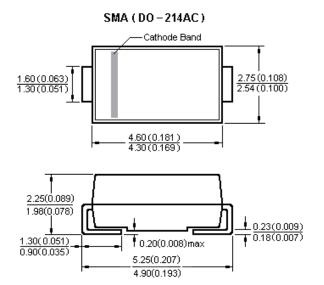


Features

- Low profile package
- Ideal for automated placement
- Ultrafast reverse recovery time
- Low power losses, high efficiency
- Low forward voltage drop
- High surge capability
- High temperatrue soldering:
 260°C/10 seconds at terminals
- Component in accordance to RoHS 2002/95/1 and WEEE 2002/96/EC

Mechanical Date

- Case: JEDEC DO-214ACmolded plastic body over passivated chip
- Terminals: Solder plated, solderable per J-STD-002B and JESD22-B102D
- Polarity: Laser band denotes cathode end



Dimentsions in millimeters and (inchs)

Maximum Ratings & Thermal Characteristics & Electrical Characteristics

(TA = 25 °C unless otherwise noted)

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	Symbol	SK12 (SS12)	SK13 (SS13)	SK14 (SS14)	SK15 (SS15)	SK16 (SS16)	SK18 (SS18)	SK110 (SS110)	UNIT		
Maximum repetitive peak reverse voltage	V_{RRM}	20	30	40	50	60	80	100	V		
Maximum RMS voltage	V_{RMS}	14	21	28	35	42	56	70	V		
Maximum DC blocking voltage	V_{DC}	20	30	40	50	60	80	100	V		
Maximum average forward rectified current	I _{F(AV)}	1							Α		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	30							Α		
Maximum instantaneous forwad voltage at 1.0A	V _F	0.55 0.70 0.85					V				
Maximum DC reverse current $T_A = 25 \degree C$	0.5							mA			
at Rated DC blocking voltage $T_A = 100^{\circ}$ C	I _R	5							mA		
Voltage rate of change (rated VR)	dv/dt	10000					V/µs				
Thermal resistance from junction to ambient	R _{θ JA}	88						°C/W			
Operating junction and storage temperature range	T _J , T _{STG}	- 65 to +150							$^{\circ}$		

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Characteristic Curves (T_A=25 ℃ unless otherwise noted)

